

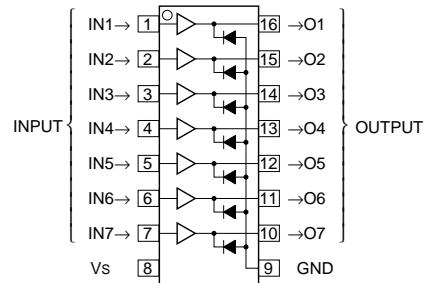
7-UNIT 500mA SOURCE TYPE DARLINGTON TRANSISTOR ARRAY WITH CLAMP DIODE

DESCRIPTION

M63800FP is a seven-circuit output-sourcing Darlington transistor array. The circuits are made of PNP and NPN transistors. This semiconductor integrated circuit performs high-current driving with extremely low input-current supply.

FEATURES

- High breakdown voltage ($BV_{CEO} \geq 50V$)
- High-current driving ($I_o(\max) = -500mA$)
- With output clamping diodes
- Driving available with CMOS IC output of 6-16V or with TTL output
- Wide operating temperature range ($T_a = -20$ to $+75^{\circ}C$)
- Output current-sourcing type

PIN CONFIGURATION

Package type 16P2N-A

APPLICATION

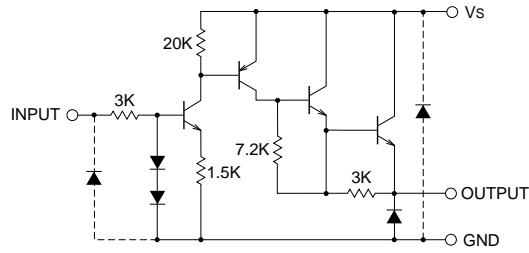
Drives of relays, printers, LEDs, fluorescent display tubes and lamps, and interfaces between MOS-bipolar logic systems and relays, solenoids, or small motors

FUNCTION

The M63800FP has seven circuits, which are made of input inverters and current-sourcing outputs. The outputs are made of PNP transistors and NPN Darlington transistors. The PNP transistor base current is constant. A spike-killer clamping diode is provided between each output pin and GND. Vs (pin 8) and GND (pin 9) are used commonly among the eight circuits.

The input has resistance of $3k\Omega$, and a maximum of 10V can be applied. The output current is 500mA maximum. Supply voltage Vs is 50V maximum.

The M63800FP is enclosed in a molded small flat package, enabling space-saving design.

CIRCUIT DIAGRAM

The seven circuits share the Vs and GND.

The diode, indicated with the dotted line, is parasitic, and cannot be used.

Unit : Ω **ABSOLUTE MAXIMUM RATINGS** (Unless otherwise noted, $T_a = -20$ ~ $+75^{\circ}C$)

Symbol	Parameter	Conditions	Ratings	Unit
V _{CEO} #	Collector-emitter voltage	Output, L	-0.5 ~ +50	V
V _s	Supply voltage		50	V
V _i	Input voltage		-0.5 ~ +10	V
I _O	Output current	Current per circuit output, H	-500	mA
I _F	Clamping diode forward current		-500	mA
V _R #	Clamping diode reverse voltage		50	V
P _d	Power dissipation	T _a = 25°C, when mounted on board	1.00	W
T _{opr}	Operating temperature		-20 ~ +75	°C
T _{tsg}	Storage temperature		-55 ~ +125	°C

: Unused I/O pins must be connected to GND.

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RECOMMENDED OPERATING CONDITIONS (Unless otherwise noted, $T_a = -20 \sim +75^\circ\text{C}$)

Symbol	Parameter	Limits			Unit
		min	typ	max	
V _s	Supply voltage	0	—	50	V
I _o	Output current (Current per 1 circuit when 7 circuits are coming on simultaneously)	0	—	-350	mA
	Duty Cycle no more than 40%	0	—	-100	
V _{ih}	"H" input voltage	2.4	5	10	V
V _{il}	"L" input voltage	0	—	0.2	V

ELECTRICAL CHARACTERISTICS (Unless otherwise noted, $T_a = -20 \sim +75^\circ\text{C}$)

Symbol	Parameter	Test conditions	Limits			Unit
			min	typ*	max	
I _s (leak) #	Supply leak current	V _s = 50V, V _i = 0.2V	—	—	100	μA
V _{ce} (sat)	Collector-emitter saturation voltage	V _s = 10V, V _i = 2.4V, I _o = -350mA	—	1.6	2.4	V
		V _s = 10V, V _i = 2.4V, I _o = -100mA	—	1.45	2.0	
I _i	Input current	V _i = 3V	—	0.6	1.0	mA
		V _i = 10V	—	2.9	5.0	
I _s	Supply current	V _s = 50V, V _i = 3V (all input)	—	5.6	15.0	mA
V _f	Clamping diode forward voltage	I _f = -350mA	—	-1.2	-2.4	V
I _r #	Clamping diode reverse current	V _r = 50V	—	—	100	μA

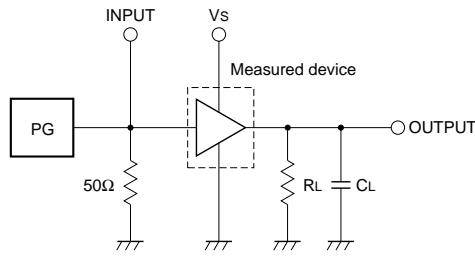
* : The typical values are those measured under ambient temperature (T_a) of 25°C . There is no guarantee that these values are obtained under any conditions.

: Unused I/O pins must be connected to GND.

SWITCHING CHARACTERISTICS (Unless otherwise noted, $T_a = 25^\circ\text{C}$)

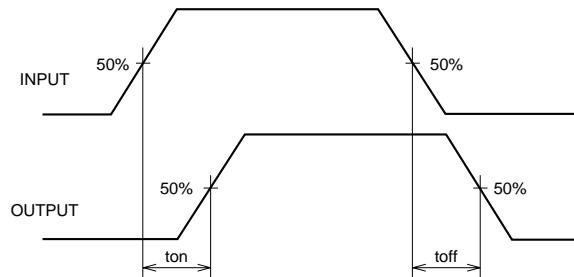
Symbol	Parameter	Test conditions	Limits			Unit
			min	typ	max	
t _{on}	Turn-on time	CL = 15pF (note 1)	—	100	—	ns
t _{off}	Turn-off time		—	4800	—	ns

NOTE 1 TEST CIRCUIT



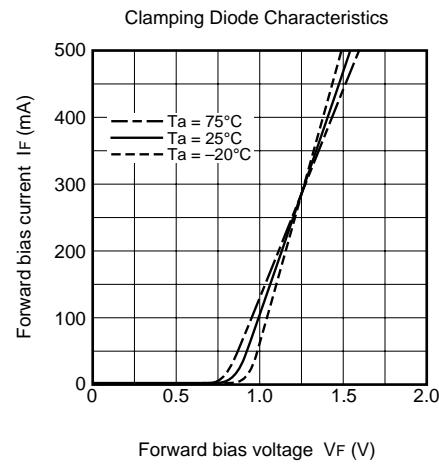
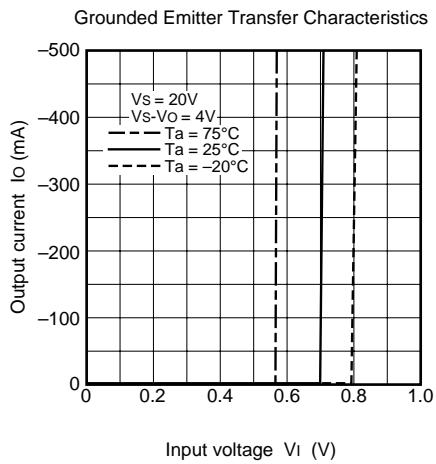
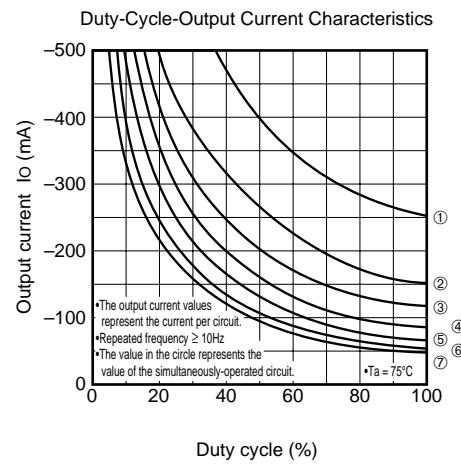
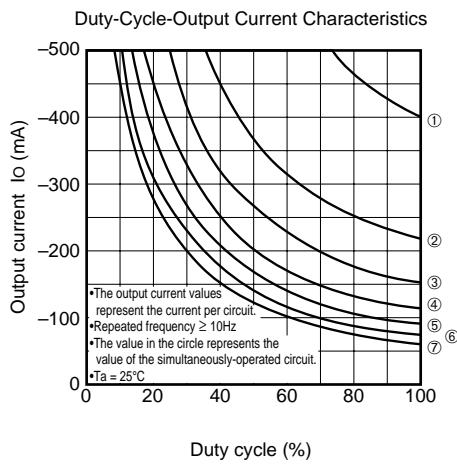
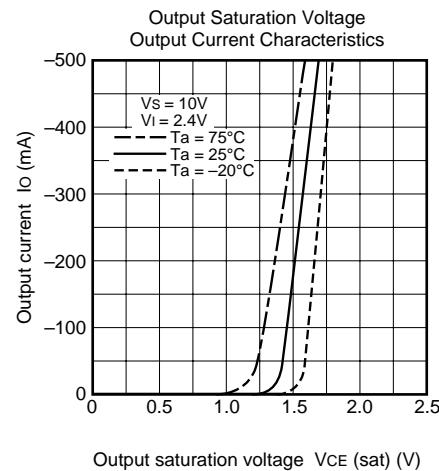
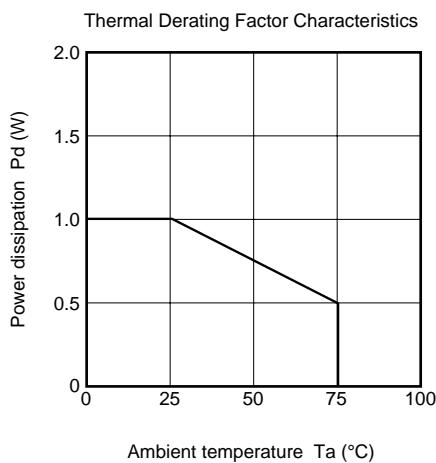
- (1) Pulse generator (PG) characteristics : PRR = 1kHz,
 $t_w = 10\mu\text{s}$, $t_r = 6\text{ns}$, $t_f = 6\text{ns}$, $Z_0 = 50\Omega$
 $V_i = 0$ to 2.4V
- (2) Input-output conditions : $R_L = 30\Omega$, $V_s = 10\text{V}$
- (3) Electrostatic capacity C_L includes floating capacitance at connections and input capacitance at probes

TIMING DIAGRAM



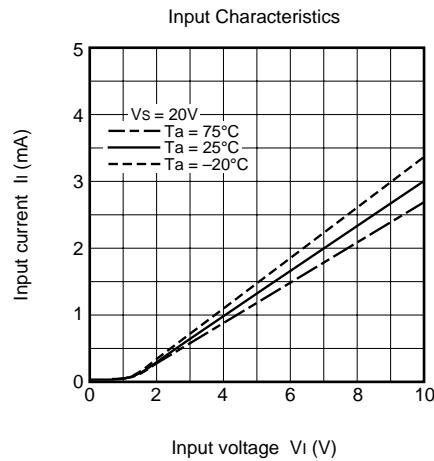
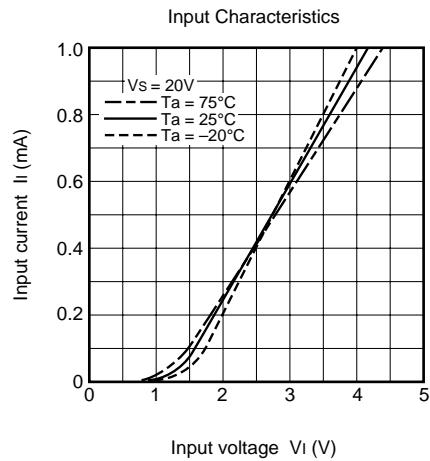
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TYPICAL CHARACTERISTICS



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